TOSHIBA Transistor Silicon NPN Epitaxial Type

2SC4681

Strobe Flash Applications Medium Power Amplifier Applications

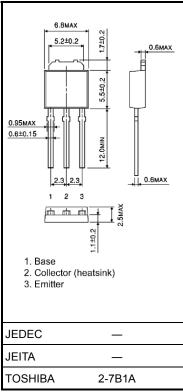
- Excellent hFE linearity
 - : hFE (1) = 200 to 600 (VCE = 2 V, IC = 0.5 A)
 - $h_{FE}(2) = 140 \text{ (min)}, 200 \text{ (typ.)} \text{ (VCE} = 2 \text{ V, IC} = 3 \text{ A)}$
- Low collector saturation voltage
 - $: V_{CE (sat)} = 0.5 \text{ V (max) (IC} = 3 \text{ A, IB} = 60 \text{ mA)}$
- Complementary to 2SA1802

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	30	V	
Collector-emitter voltage		V _{CES}	30	V	
		V _{CEO}	10		
Emitter-base voltage		V_{EBO}	6	>	
Collector current	DC	I _C	3	А	
	Pulse (Note)	I _{CP}	6		
Base current		Ι _Β	0.5	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	1 0	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)

Unit: mm

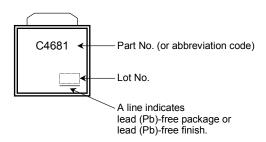


Weight: 0.36 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 30 V, I _E = 0	_	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 6 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage	V_{CEO}	I _C = 10 mA, I _B = 0	10	_	_	V
DC current gain	h _{FE (1)}	V _{CE} = 20 V, I _C = 0.5 A	200	_	600	
	h _{FE (2)}	V _{CE} = 2 V, I _C = 3 A	140	200	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 3 A, I _B = 60 mA	_	0.33	0.5	٧
Base-emitter voltage	V_{BE}	V _{CE} = 2 V, I _C = 3 A	_	0.92	1.2	V
Transition frequency	f _T	V _{CE} = 2 V, I _C = 0.5 A	_	150	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	27	_	pF

Marking



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